

Cylindrical Photoelectric Sensor

The CY series of photoelectric sensors has an M18 thread size for convenient mounting. Thrubeam, diffuse reflective, and retroreflective types allow for a wide range of applicable uses. They are available in AC and DC types with three output options (NPN, PNP, or Thyristor). A pigtailed type sensor with an M12 connector is also available, providing an easy to replace option.

Its IP67 construction allow for installation in tough environments and can be washed down with water. In addition, it has strong resistance against vibration. The connector also has IP67 protection.

Convenient options such as the side-view attachment and slit masks enhance the usability of the CY series.

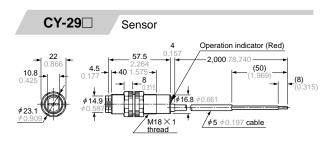
Model Name	Model Pic	Туре	Output Operation	Output Configuration	Emitting Element	Max. Range (mm)	Max. Range (in)
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CY-11A		Thrubeam AC Type	Light-ON	AC Thyristor	Infrared LED	12000	472.4
CY-11A-J		Thrubeam AC Type, M12 Quick Disconnect	Light-ON	AC Thyristor	Infrared LED	12000	472.4
CY-11B		Thrubeam AC Type	Dark-ON	AC Thyristor	Infrared LED	12000	472.4
CY-11B-J		Thrubeam AC Type, M12 Quick Disconnect	Dark-ON	AC Thyristor	Infrared LED	12000	472.4
CY-12A		Diffuse Reflective AC Type	Light-ON	AC Thyristor	Infrared LED	120	4.7
CY-12A-J		Diffuse Reflective AC Type, M12 Quick Disconnect	Light-ON	AC Thyristor	Infrared LED	120	4.7
CY-12B		Diffuse Reflective AC Type	Dark-ON	AC Thyristor	Infrared LED	120	4.7
CY-12B-J		Diffuse Reflective AC Type, M12 Quick Disconnect	Dark-ON	AC Thyristor	Infrared LED	120	4.7
CY-17A		Retro- Reflective AC Type	Light-ON	AC Thyristor	Infrared LED	3000	118.1
CY-17A-J		Retro- Reflective AC Type, M12 Quick Disconnect	Light-ON	AC Thyristor	Infrared LED	3000	118.1

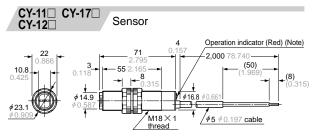
CY-29		Polarized Retro- Reflective DC	Light-ON/Dark- ON	NPN	Red LED	1500	59.1
CY-27		Retro- Reflective DC Type	Light-ON/Dark- ON	NPN	Infrared LED	3000	118.1
CY-22		Diffuse Reflective DC Type	Light-ON/Dark- ON	NPN	Infrared LED	120	4.7
CY-21-PN-J	-CID-CID-	Thrubeam DC Type, M12 Quick Disconnect	Light-ON/Dark- ON	PNP	Infrared LED	12000	472.4
CY-21-PN		Thrubeam DC Type	Light-ON/Dark- ON	PNP	Infrared LED	12000	472.4
CY-21-J		Thrubeam DC Type, M12 Quick Disconnect	Light-ON/Dark- ON	NPN	Infrared LED	12000	472.4
CY-21		Thrubeam DC Type	Light-ON/Dark- ON	NPN	Infrared LED	12000	472.4
CY-19B-J		Polarized Retro- Reflective AC Type, M12 Quick Disconnect	Dark-ON	AC Thyristor	Red LED	1500	59.1
CY-19B		Polarized Retro- Reflective AC Type	Dark-ON	AC Thyristor	Red LED	1500	59.1
CY-19A-J		Polarized Retro- Reflective AC Type, M12 Quick Disconnect	Light-ON	AC Thyristor	Red LED	1500	59.1
CY-19A		Polarized Retro- Reflective AC Type	Light-ON	AC Thyristor	Red LED	1500	59.1
CY-17B-J		Retro- Reflective AC Type, M12 Quick Disconnect	Dark-ON	AC Thyristor	Infrared LED	3000	118.1
CY-17B		Retro- Reflective AC Type	Dark-ON	AC Thyristor	Infrared LED	3000	118.1

DIMENSIONS (Unit: mm in)

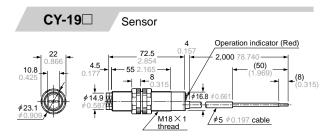
CY-21 CY-27 Sensor Sensor 4 Operation indicator (Red) (Note) 2,200 78,740 (50) 1,18 + 401,575 + 1,28 + 1,49 + 1,

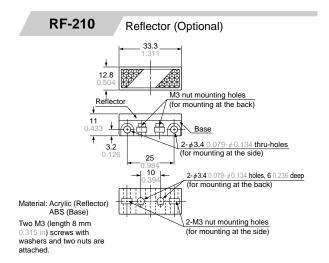
Note: It is the emitting indicator (red) on the emitter of the thru-beam type sensor.

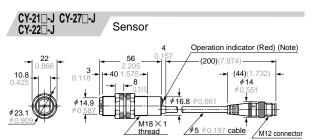




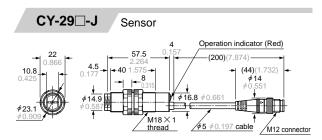
Note: It is the power indicator (red) on the emitter of the thru-beam type sensor.

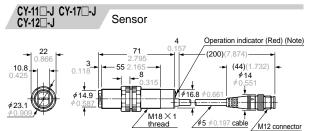




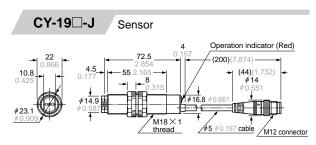


Note: It is the emitting indicator (red) on the emitter of the thru-beam type sensor.

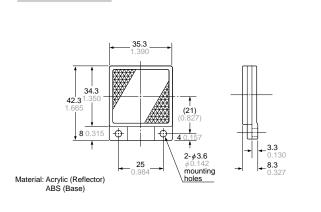




Note: It is the power indicator (red) on the emitter of the thru-beam type sensor.



Reflector (Optional)



RF-220



SPECIFICATIONS

DC supply type

Type NPN output type PNP output type to sensing axis) nption category eration it protection		0 mA less (between output and 0 V) less (at 100 mA sink current)	Residual voltage: 1.5 V or I	CY-22 CY-22-PN 120 mm 4.724 in (Note 2) Opaque, translucent or transparent object 15 % or less of operation distance 0.3 mm 0.012 in or less 100 mA or less (between output and + Veless (at 100 mA source current)					
PNP output type to sensing axis) pption category cration	CY-21-PN 12 m 39.370 ft \$8 mm \$0.315 in or more opaque object Emitter: 20 mA or less Receiver: 25 mA or less <npn output="" type=""> NPN open-collector transistor • Maximum sink current: 100 • Applied voltage: 30 V DC or</npn>	CY-27-PN 3 m 9.843 ft (Note 1) \$50 mm \$\phi 1.969 \text{ in or more opaque or translucent object (Note 1)} 0.1 mm 0.004 in or less 10 to 30 V DC Ripple of the property of	CY-29-PN 1.5 m 4.921 ft (Note 1) \$50 mm \$1.969 in or more opaque, translucent or specular object (Note 1) ple P-P 10 % or less 25 mA or less <pnp output="" type=""> PNP open-collector transistor • Maximum source current: • Applied voltage: 30 V DC o • Residual voltage: 1.5 V or l</pnp>	CY-22-PN 120 mm 4.724 in (Note 2) Opaque, translucent or transparent object 15 % or less of operation distance 0.3 mm 0.012 in or less					
to sensing axis) apption category pration	12 m 39.370 ft	3 m 9.843 ft (Note 1) \$\phi 50 \text{ mm } \phi 1.969 \text{ in or more opaque or translucent object (Note 1)} 0.1 mm 0.004 \text{ in or less} 10 to 30 V DC Ripp 0 mA less (between output and 0 V) less (at 100 mA sink current) DC-12 c	1.5 m 4.921 ft (Note 1)	120 mm 4.724 in (Note 2) Opaque, translucent or transparent object 15 % or less of operation distance 0.3 mm 0.012 in or less 100 mA or less (between output and + \)					
nption	### ### ### ### #### ################	450 mm 41.969 in or more opaque or translucent object (Note 1) 0.1 mm 0.004 in or less 10 to 30 V DC Ripp 0 mA less (between output and 0 V) less (at 100 mA sink current) DC-12 c	\$50 mm \$1.969 in or more opaque, translucent or specular object (Note 1) ple P-P 10 % or less 25 mA or less <pnp output="" type=""> PNP open-collector transistor • Maximum source current: • Applied voltage: 30 V DC o • Residual voltage: 1.5 V or I</pnp>	Opaque, translucent or transparent object 15 % or less of operation distance 0.3 mm 0.012 in or less 100 mA or less (between output and + \text{V}					
nption	Emitter: 20 mA or less Receiver: 25 mA or less <npn output="" type=""> NPN open-collector transistor • Maximum sink current: 100 • Applied voltage: 30 V DC or</npn>	or translucent object (Note 1) 0.1 mm 0.004 in or less 10 to 30 V DC Ripp 0 mA less (between output and 0 V) less (at 100 mA sink current) DC-12 c	ple P-P 10 % or less 25 mA or less PNP output type> PNP open-collector transistor • Maximum source current: • Applied voltage: 30 V DC o • Residual voltage: 1.5 V or I	or transparent object 15 % or less of operation distance 0.3 mm 0.012 in or less 100 mA or less (between output and + \					
nption	Receiver: 25 mA or less <npn output="" type=""> NPN open-collector transistor • Maximum sink current: 100 • Applied voltage: 30 V DC or</npn>	10 to 30 V DC Ripp 0 mA less (between output and 0 V) less (at 100 mA sink current)	25 mA or less <pnp output="" type=""> PNP open-collector transistor • Maximum source current: • Applied voltage: 30 V DC o • Residual voltage: 1.5 V or I</pnp>	0.3 mm 0.012 in or less 100 mA Ir less (between output and + \					
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category	Receiver: 25 mA or less <npn output="" type=""> NPN open-collector transistor • Maximum sink current: 100 • Applied voltage: 30 V DC or</npn>) mA less (between output and 0 V) less (at 100 mA sink current) DC-12 c	25 mA or less <pnp output="" type=""> PNP open-collector transistor • Maximum source current: • Applied voltage: 30 V DC o • Residual voltage: 1.5 V or I</pnp>	or less (between output and $+$ \					
category	Receiver: 25 mA or less <npn output="" type=""> NPN open-collector transistor • Maximum sink current: 100 • Applied voltage: 30 V DC or</npn>	less (between output and 0 V) less (at 100 mA sink current) DC-12 c	<pnp output="" type=""> PNP open-collector transistor • Maximum source current: • Applied voltage: 30 V DC o • Residual voltage: 1.5 V or I</pnp>	or less (between output and $+$ \					
eration	NPN open-collector transistor • Maximum sink current: 100 • Applied voltage: 30 V DC or	less (between output and 0 V) less (at 100 mA sink current) DC-12 c	PNP open-collector transistor • Maximum source current: • Applied voltage: 30 V DC o • Residual voltage: 1.5 V or I	or less (between output and $+$ \					
eration			or DC-13						
		Selectable either Light-ON or	DC-12 or DC-13						
it protection	tion Incorporated								
	Incorporated								
		2 ms (or less						
ion halt) function	Incorporated	porated ————							
ator	Red LED (lights up when the output is ON)								
itor	Red LED (lights up during beam emission)								
egree		3 (Industrial	environment)						
	IP67 (IEC)								
mperature	-25 to +55 °C -13 to +	- 131 °F (No dew condensation of	or icing allowed), Storage: - 30 to	o + 70°C − 22 to + 158 °F					
umidity	35 to 85 % RH, Storage: 35 to 85 % RH								
uminance	Sunlight: 10,000 ℓ	x at the light-receiving face, Inc	ncandescent light: 3,000 ℓx at the light-receiving face						
	EN 50081-2, EN 50082-2, EN 60947-5-2								
hstandability	1,000 V AC for one min. between all supply terminals connected together and enclosure								
esistance	1111								
esistance	10 to 500 Hz frequency, 1.5 mm 0.059 in amplitude (10 G max.) in X, Y and Z directions for two hours								
stance	500 m/s ² acceleration (50 G approx.) in X, Y and Z directions for three times each								
nt									
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	Emitter: 90 g approx.	100 g approx.							
		<u> </u>							
	midity minance hstandability esistance esistance tance	midity minance Sunlight: 10,000 ℓ mstandability 1,000 V AC esistance 20 MΩ, or more, with sistance 10 to 500 Hz frequent stance 500 m/sint Infrared LEC Enclosure: PBT, Lec 0.34 mm Extension up to total 100 m 33	midity 35 to 85 % RH, Storement Sunlight: 10,000 ℓx at the light-receiving face, Inc. EN 50081-2, EN 500 histandability 1,000 V AC for one min. between all supply esistance 20 MΩ, or more, with 250 V DC megger between all sistance 10 to 500 Hz frequency, 1.5 mm 0.059 in amplitude (1 stance) 500 m/s² acceleration (50 G approx.) in 2 in the stance of the sta	midity 35 to 85 % RH, Storage: 35 to 85 % RH uninance Sunlight: 10,000 ℓx at the light-receiving face, Incandescent light: 3,000 ℓx at the EN 50081-2, EN 50082-2, EN 60947-5-2 Instandability 1,000 V AC for one min. between all supply terminals connected together an esistance 20 MΩ, or more, with 250 V DC megger between all supply terminals connected together and supply terminals connected together and sistance 10 to 500 Hz frequency, 1.5 mm 0.059 in amplitude (10 G max.) in X, Y and Z directions for three times and the supply terminals connected together and sistance 500 m/s² acceleration (50 G approx.) in X, Y and Z directions for three times and the supply terminals connected together and the sistance 500 m/s² acceleration (50 G approx.) in X, Y and Z directions for three times and the supply terminals connected together and the sistance 500 m/s² acceleration (50 G approx.) in X, Y and Z directions for three times and the supply terminals connected together and the sistance 500 m/s² acceleration (50 G approx.) in X, Y and Z directions for three times and the supply terminals connected together and the sistance and the supply terminals connected together and the sistance and the supply terminals connected together and th					

NOTE: Reflector is not supplied with the retroreflective type sensor. Please select the suitable reflector or reflective tape from the options.

Notes: 1) The sensing range and the sensing object of the retroreflective type sensor are specified for the **RF-230** reflector (optional).

2) The sensing range of the diffuse reflective type sensor is specified for white non-glossy paper (200 × 200 mm 7.874 × 7.874 in) as the object.